

## LL103A - LL103C

### FEATURES :

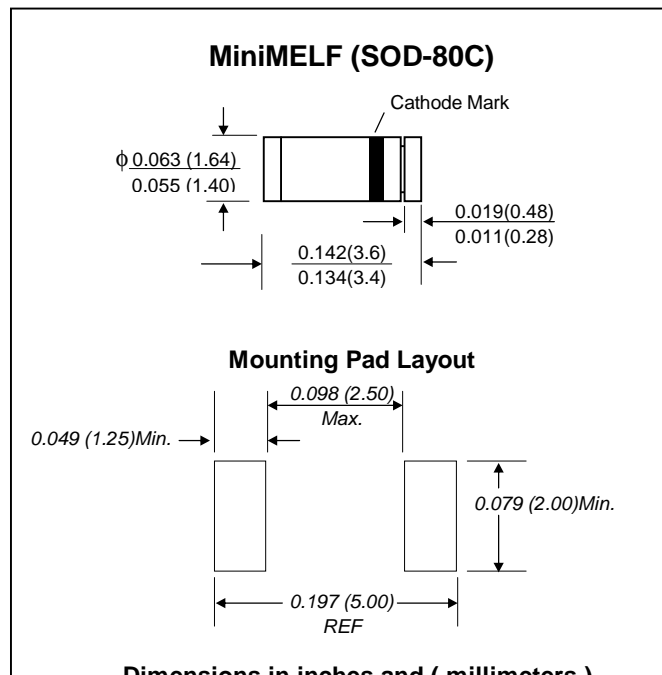
- For general purpose applications
- The LL103A, B, C series is a metal-on-silicon Schottky barrier device which is protected by a PN junction guard ring.
  - The low forward voltage drop and fast switching make it ideal for protection of MOS devices, steering, biasing and coupling diodes for fast switching and low logic level applications.
- Other applications are click suppression, efficient full wave bridges in telephone subsets, and blocking diodes in rechargeable low voltage battery systems.
- These diodes are also available in the DO-35 case with type designation SD103A, B, C
- Pb / RoHS Free

### MECHANICAL DATA :

**Case:** MiniMELF Glass Case (SOD-80C)

**Weight:** approx. 0.05g

## SCHOTTKY BARRIER DIODES



### Maximum Ratings and Thermal Characteristics (Rating at 25 °C ambient temperature unless otherwise specified.)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	LL103A	40	V
	LL103B	30	
	LL103C	20	
Single Cycle Surge 60 Hz Sine Wave	$I_{FSM}$	15	A
Power Dissipation (Infinite Heatsink)	PD	400 <sup>(1)</sup>	mW
Thermal Resistance Junction to Ambient Air	$R_{\theta JA}$	300 <sup>(1)</sup>	°C/W
Junction Temperature	$T_J$	125	°C
Storage temperature range	$T_S$	-55 to + 150	°C

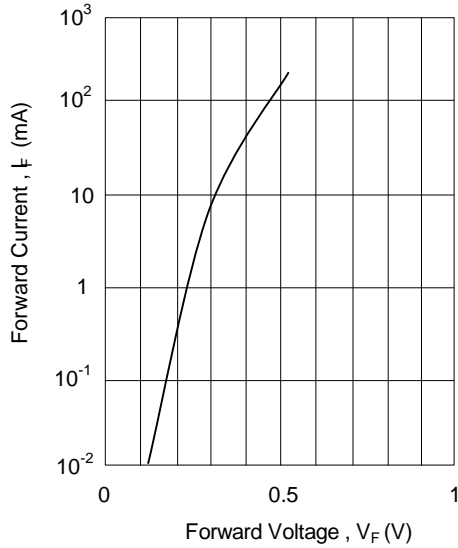
Note: (1) Valid provided that electrodes are kept at ambient temperature.

### Electrical Characteristics ( $T_J = 25^\circ\text{C}$ unless otherwise noted)

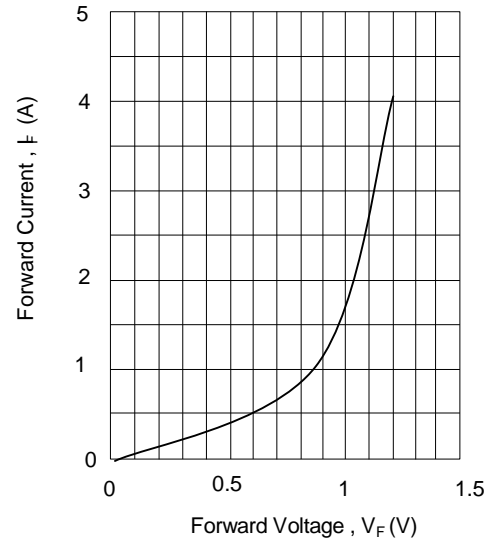
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Current	LL103A	$V_R = 30\text{ V}$	-	-	5	$\mu\text{A}$
	LL103B	$V_R = 20\text{ V}$	-	-	5	
	LL103C	$V_R = 10\text{ V}$	-	-	5	
Forward Voltage Drop	$V_F$	$I_F = 20\text{mA}$	-	-	0.37	V
		$I_F = 200\text{mA}$	-	-	0.6	
Diode Capacitance	Cd	$V_R = 0\text{ V}, f = 1\text{MHz}$	-	50	-	pF
Reverse Recovery Time	$T_{rr}$	$I_F = I_R = 5\text{mA}$ to 200mA recover to $0.1I_R$	-	10	-	ns

### RATING AND CHARACTERISTIC CURVES ( LL103A - LL103C )

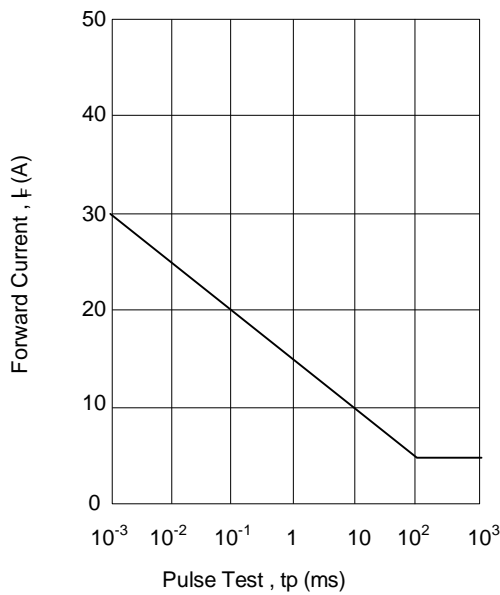
Typical variation of forward current and forward voltage for primary conduction through the schottky barrier



Typical high current forward conduction curve  
 $t_p = 300ms$ , duty cycle = 2%



Typical non repetitive forward surge current versus pulse width  
Rectangular pulse



Typical variation of reverse current at various temperatures

